

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20160202001 Qualification of ASEN as Additional Assembly and Test Site for Select UQFN Package Devices Change Notification / Sample Request

Date: 2/5/2016

To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www admin team@list.ti.com).

Sincerely,

PCN Team SC Business Services

20160202001 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
TS3USB221RSER	null
TPD6E001RSER	null
SN74AVC4T774RSVR	null
TS3USB30ERSWR	null
TCA6408ARSVR	null
TS3USB221ARSER	null
TXB0104RUTR	null
SN74AVC4T245RSVR	null
SN74AVC2T245RSWR	null
TS3USB221ERSER	null

Technical details of this Product Change follow on the next page(s).

PCN	Number:		201	.6020200	1			PCN Date: 0)2/05/2016
Title	Title: Qualification of ASEN as Additional Assembly and Test Site for Select UQFN Package Devices					N Package			
Cust	Customer Contact: PCN Manager Dept: Quality Services								
Prop	Proposed 1 st Ship Date: 05/05/2016 Estimated Sample Availability: Date Provided at Sample request								
Char	nge Type:					-			
\boxtimes	Assembly				Design			Wafer Bump	Site
	Assembly	Process	;		Data Sheet			Wafer Bump	Material
	Assembly	Materia	ls		Part number of	hange		Wafer Bump	Process
	Mechanica	al Specif	ication		Test Site			Wafer Fab Sit	te
\boxtimes	Packing/S	hipping,	/Labeli	ng	Test Process			Wafer Fab Ma	aterials
								Wafer Fab Pro	ocess
					PCN Deta	ls			
Desc	cription o	f Chang	je:						
and 1		or select	device	es listed i	nouncing the qua n the "Product A				
Ass	embly Site	Assen		te Origin	Assembly Coun	ry Code	As	ssembly Site City	<u>/</u>
	UTAC		NSE		TH			Bangkok	
	JCET		JCE		CN			Jiangyin	
	HANA		HNT		TH			Ayutthaya	
	ASEN		ASN		CN			Suzhou	
Material Differences:					1				
- idee				ITAC	1CFT	НΛ	NΛ	ASEN	
	ount Comr	ound		JTAC 70027	JCET	HA		ASEN	
Мо	ount Comp		PZ	20037	120402001600	400	173	1400238112	
Мо	lold Comp	ound	PZ CZ	Z0037 Z0136	120402001600 120903003709	400 450	173 176	1400238112 1801512111	
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Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS

MADE IN: Malaysia 2DC: 2Q:

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

5A (L)T0:3750



(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483SI2

(2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

SN74AVC2T245RSWR	TPD13S523RSVR	TS3USB221RSER	TXB0104RUTR
SN74AVC4T245RSVR	TPD6E001RSER	TS3USB30ERSWR	TXB0304RUTR
SN74AVC4T774RSVR	TS3USB221ARSER	TS5A23159RSER	
TCA6408ARSVR	TS3USB221ERSER	TS5USBA224RSWR	

Qualification Report

ASEN RSE Package (Hong-how HP20VI-RH screen print)

Qualification Approved on 1/21/2016

Product Attributes

Attributes	Qual Device: TS3USB221ERSER	QBS Product Reference: TS3USB221ARSE	QBS Product Reference: TS3USB221EDRC	QBS Package Reference: SN74AVC4T245RSVR
Assembly Site	ASEN	NSE	TIM (MAL)	ASEN
Package Family	QFN	QFN	QFN	-
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V 0	UL 94 V-0
Wafer Fab Supplier	FFAB	FFAB	FFAB	FFAB
Wafer Process	50B10	50b10.13	50B10.13	ASLC10

- QBS: Qual By Similarity
- Qual Devices qualified at LEVEL1-260C: TS3USB221RSER, TS3USB221ERSER
- Qual Devices qualified at LEVEL1-260CG: TS3USB221ARSER, TS5A23159RSER

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TS3USB221ERSER	QBS Product Reference: TS3USB221ARSE	QBS Product Reference: TS3USB221EDRC	QBS Package Reference: SN74AVC4T245RSVR
AC	Autoclave 121C	96 Hours	-	3/231/0	-	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	-	Pass	Pass	Pass
FLAM	Flammability (IEC 695-2-2)	1	-	-	-	3/15/0
FLAM	Flammability (UL 94V-0)	1	-	-	-	3/15/0
FLAM	Flammability (UL-1694)		-	-	-	3/15/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	-	3/231/0
HBM	ESD - HBM	7000 V	-	3/9/0	1/3/0	-
HBM	ESD - HBM -HIGH	12000 V	-	3/9/0	-	-
CDM	ESD - CDM	1500 V	-	3/9/0	1/3/0	-
HTOL	Life Test, 150C	300 Hours	-	3/348/0	-	3/231/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	-	-	3/231/0
HTSL	High Temp. Storage Bake, 150C	1000 Hours	-	3/231/0	-	-
LU	Latch-up	(per JESD78)	-	3/9/0	1/6/0	-
PD	Physical Dimensions		3/15/0	-	-	3/15/0
SD	Solderability	Pb Free	-	-	-	3/66/0
TC	Temperature Cycle, - 65/150C	500 Cycles	-	3/231/0	-	3/231/0
WBP	Bond Strength	Wires	3/228/0	-	-	3/228/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Qualification Report

ASEN RSV Package (Hong-how HP20VI-RH screen print)

Qualification Approved on 1/21/2016

Product Attributes

Attributes	Qual Device: SN74AVC4T245RSVR	QBS Product Reference: SN74AVC4T245PWR	QBS Product Reference: TCA6408APWR
Assembly Site	ASEN	MLA	TIM
Package Family	-	TSSOP	TSSOP
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	FFAB	FFAB	FFAB
Wafer Process	ASLC10	ASLC10	LBC7

⁻ QBS: Qual By Similarity

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: SN74AVC4T245RSV R	QBS Product Reference: SN74AVC4T245PWR	QBS Product Reference: TCA6408APWR
AC	Autoclave 121C	96 hours	3/231/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	Pass
FLAM	Flammability (IEC 695-2-2)		3/15/0	-	-
FLAM	Flammability (UL 94V-0)		3/15/0	=	-
FLAM	Flammability (UL-1694)		3/15/0	-	-
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0	=	-
HBM	ESD - HBM	3000 V	=	=	1/3/0
HBM	ESD - HBM -HIGH	8000 V	-	1/3/0	-
CDM	ESD - CDM	1500 V	-	1/3/0	1/3/0
HTOL	Life Test, 150C	300 Hours	3/231/0	-	1/77/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/231/0	-	-
LU	Latch-up	(per JESD78)	-	1/6/0	1/6/0
PD	Physical Dimensions		3/15/0	=	-
SD	Solderability	Pb Free	3/66/0	=	-
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0	=	1/77/0
WBP	Bond Strength	Wires	3/228/0	-	-

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

⁻ Qual Devices qualified at LEVEL1-260C: SN74AVC4T245RSVR, SN74AVC4T774RSVR, TCA6408ARSVR

⁻ The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

⁻ The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

⁻ The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Qualification Report

ASEN RSW Package (Hong-how HP20VI-RH screen print)

Qualification Approved on 1/21/2016

Product Attributes

Attributes	Qual Device: TS3USB30ERSWR	QBS Package Reference: SN74AVC4T245RSVR
Assembly Site	ASEN	ASEN
Package Family	QFN	-
Flammability Rating	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	FFAB	FFAB
Wafer Process	50b10	ASLC10

- QBS: Qual By Similarity
- Qual Devices qualified at LEVEL1-260C: TS3USB30ERSWR, SN74AVC2T245RSWR

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TS3USB30ERSWR	QBS Package Reference: SN74AVC4T245RSVR
AC	Autoclave 121C	96 Hours	-	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	-	Pass
FLAM	Flammability (IEC 695-2-2)		-	3/15/0
FLAM	Flammability (UL 94V-0)		-	3/15/0
FLAM	Flammability (UL-1694)		-	3/15/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0
HTOL	Life Test, 150C	300 Hours	-	3/231/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0
PD	Physical Dimensions		3/15/0	3/15/0
SD	Solderability	Pb Free	=	3/66/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0
WBP	Bond Strength	Wires	3/228/0	3/228/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com